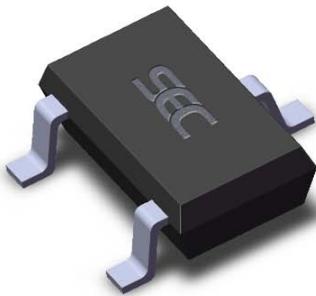


### Features and Benefits

- 3.5V to 24V Operation
- -40°C to 150°C Superior temperature operation
- CMOS technology
- Low current consumption
- Chopper-stabilized amplifier stage
- Open drain output
- Low sensitivity
- Small Size SOT23 3L or SIP 3L
- both RoHS compliant packages

### Application Examples

- Automotive, Consumer and Industrial
- Solid-state switch
- Brushless DC motor commutation
- Speed detection
- Angular position detection
- Proximity detection
- Current detector

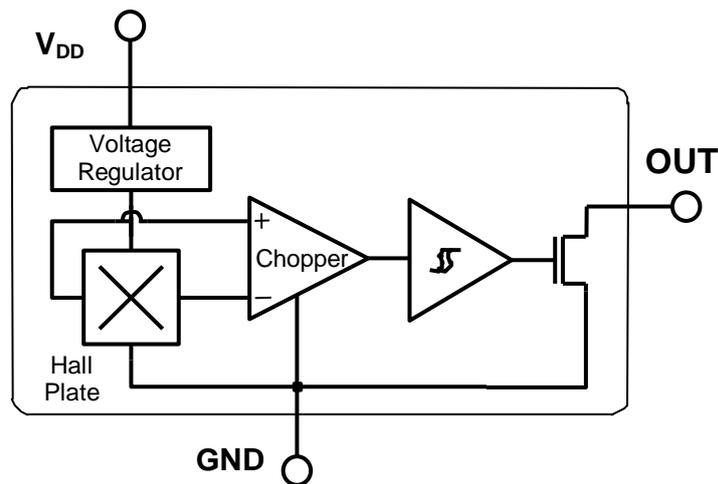


3 pin SOT23 (suffix SO)



3 pin SIP (suffix UA)

### Functional Block Diagram



SIP Package	SOT Package
Pin 1 – V <sub>DD</sub>	Pin 1 – V <sub>DD</sub>
Pin 2 – GND	Pin 2 – OUT
Pin 3 – OUT	Pin 3 – GND

## General Description

The SS1344 is a unipolar Hall-effect sensor IC fabricated from CMOS technology. The device integrates a voltage regulator, Hall sensor with dynamic offset cancellation system, small signal amplifier, Schmitt trigger and an open-drain output driver. With suitable output pull up, they can be used with bipolar or CMOS logic circuits.

These Hall-effect switches are monolithic integrated circuits with tighter magnetic specifications, designed to operate continuously over extended temperatures to +150°C, and are more stable with both

temperature and supply voltage changes. The unipolar switching characteristic makes these devices ideal for use with a simple bar or rod magnet.

Thanks to its wide operating voltage range and extended choice of temperature range, it is quite suitable for use in automotive, industrial and consumer applications.

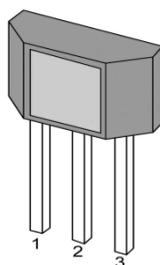
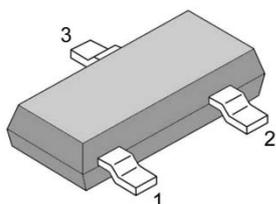
The device is delivered in a Small Outline Transistor (SOT) or in a Plastic Single In Line (SIP 3L flat). Both 3-lead packages are RoHS compliant.

## Glossary of Terms

MilliTesla (mT), Gauss	Units of magnetic flux density: 1mT = 10 Gauss
RoHS	Restriction of Hazardous Substances
Operating Point (BOP)	Magnetic flux density applied on the branded side of the package which turns the output driver ON ( $V_{OUT} = V_{DSon}$ )
Release Point (BRP)	Magnetic flux density applied on the branded side of the package which turns the output driver OFF ( $V_{OUT} = \text{high}$ )

**Pins Definition and Description**

SOT Pin №	SIP Pin №	Name	Type	Function
1	1	V <sub>DD</sub>	Supply	Supply Voltage pin
2	3	OUT	Output	Open Drain Output pin
3	2	GND	Ground	Ground pin


**Absolute Maximum Ratings**

Parameter	Symbol	Value	Units
Supply Voltage	V <sub>DD</sub>	28	V
Supply Current	I <sub>DD</sub>	50	mA
Output Voltage	V <sub>OUT</sub>	28	V
Output Current	I <sub>OUT</sub>	50	mA
Storage Temperature Range	T <sub>S</sub>	-65 to 170	°C

Operating Temperature Range	Symbol	Value	Units
Temperature Suffix “E”	T <sub>A</sub>	-40 to 85	°C
Temperature Suffix “K”	T <sub>A</sub>	-40 to 125	°C
Temperature Suffix “L”	T <sub>A</sub>	-40 to 150	°C

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum- rated conditions for extended periods may affect device reliability.

## General Electrical Specifications

DC Operating Parameters  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 3.5\text{V to } 24\text{V}$  (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Supply Voltage	$V_{DD}$	Operating	3.5		24	V
Supply Current	$I_{DD}$	$B < B_{RP}$	1.5	2.5	5	mA
Output Saturation Voltage	$V_{DSon}$	$I_{OUT} = 20\text{mA}$ , $B > B_{OP}$		0.4	0.5	V
Output Leakage Current	$I_{OFF}$	$B < B_{RP}$ , $V_{OUT} = 24\text{V}$		0.01	10	$\mu\text{A}$
Output Rise Time	$t_r$	$R_L = 1\text{k}\Omega$ , $C_L = 20\text{pF}$		0.25		$\mu\text{s}$
Output Fall Time	$t_f$	$R_L = 1\text{k}\Omega$ , $C_L = 20\text{pF}$		0.25		$\mu\text{s}$

## Magnetic Specifications

DC Operating Parameters  $V_{DD} = 3.5$  to  $24\text{V}$  (unless otherwise specified)

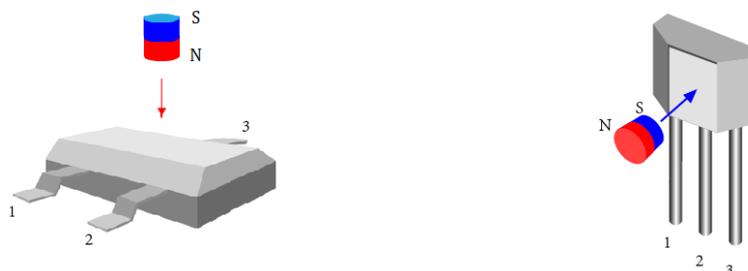
Package	Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
UA	Operating Point	$B_{OP}$	$T_a = 25^\circ\text{C}$ , $V_{dd} = 12\text{V DC}$	70		150	G
	Release Point	$B_{RP}$		20		100	G
	Hysteresis	$B_{HYST}$			50		G
SO	Operating Point	$B_{OP}$	$T_a = 25^\circ\text{C}$ , $V_{dd} = 12\text{V DC}$	-150		-70	G
	Release Point	$B_{RP}$		-100		-20	G
	Hysteresis	$B_{HYST}$			50		G

## Output Behavior versus Magnetic Pole

DC Operating Parameters  $T_A = -40^\circ\text{C to } 150^\circ\text{C}$ ,  $V_{DD} = 3.5$  to  $24\text{V}$  (unless otherwise specified)

Test Conditions (UA)	Test Conditions (SO)	OUT
$B < B_{RP}$	$B > B_{RP}$	High
$B > B_{OP}$	$B < B_{OP}$	Low

The SOT-23 device is reversed from the UA package. The SOT-23 output transistor will be turned on (drops low) in the presence of a sufficiently strong North pole magnetic field applied to the marked face.



## Application Information

It is strongly recommended that an external bypass capacitor be connected (in close proximity to the Hall sensor) between the supply ( $V_{DD}$  Pin) and ground (GND Pin) of the device to reduce both external noise and noise generated by the chopper stabilization technique. As is shown in the following figure, a  $0.1\mu\text{F}$  capacitor is typical.

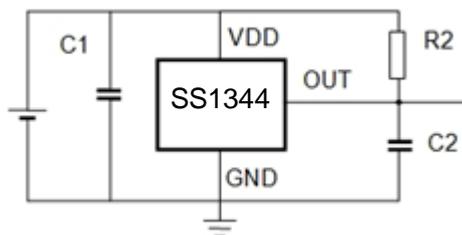
For reverse voltage protection, it is recommended to connect a resistor or a diode in series with the  $V_{DD}$  pin. When using a resistor, three points are important:

- the resistor has to limit the reverse current to 50mA maximum ( $V_{CC} / R1 \leq 50\text{mA}$ )
- the resulting device supply voltage  $V_{DD}$  has to be higher than  $V_{DD}$  min ( $V_{DD} = V_{CC} - R1 * I_{DD}$ )
- the resistor has to withstand the power dissipated in reverse voltage condition ( $P_D = V_{CC}^2 / R1$ )

When using a diode, a reverse current cannot flow and the voltage drop is almost constant ( $\approx 0.7\text{V}$ ).

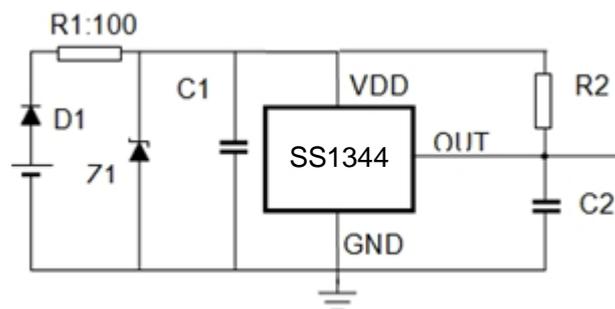
Therefore, a  $100\Omega/0.25\text{W}$  resistor for 5V application and a diode for higher supply voltage are recommended.

### Typical Three-Wire Application Circuit



When a weak power supply is used or when the device is intended to be used in noisy environment, it is recommended that following figure is used.

### Automotive and Severe Environment Protection Circuit



The low-pass filter formed by R1 and C1 and the Zener diode Z1 bypass the disturbances or voltage spikes occurring on the device supply voltage  $V_{DD}$ . The diode D1 provides additional reverse voltage protection. Both solutions provide the required reverse voltage protection.

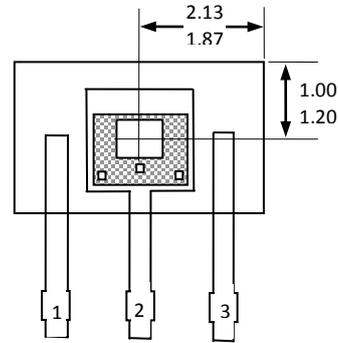
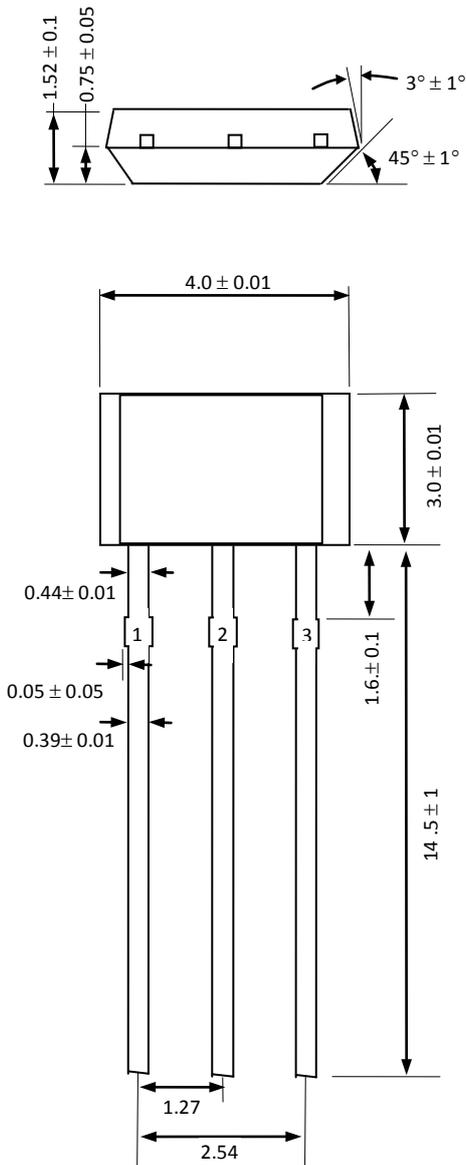
## ESD Precautions

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD).

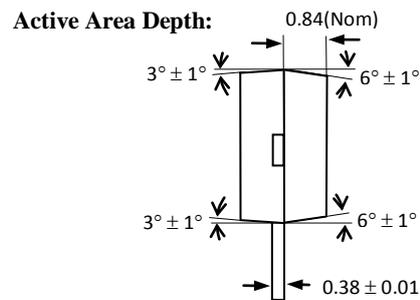
Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

### Package Information

#### Package UA, 3-Pin SIP:



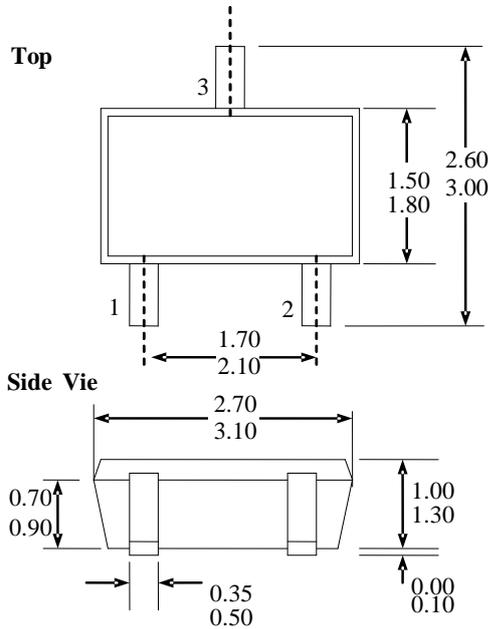
Sensor Location



**Notes:**

- 1). Controlling dimension : mm ;
- 2). Leads must be free of flash and plating voids ;
- 3). Do not bend leads within 1 mm of lead to package interface ;
- 4). PINOUT: Pin 1  $V_{DD}$   
Pin 2 GND  
Pin 3 Output

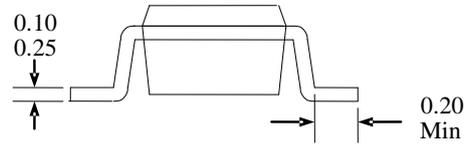
### Package SO, 3-Pin SOT-23:



#### Notes

- 1). PINOUT: Pin 1 V<sub>DD</sub>  
Pin 2 Output  
Pin 3 GND
- 2). All dimensions are in millimeters;

#### End View



## Ordering Information

Part No.	Pb-free	Temperature Code	Package Code	Packing
SS1344ESOT	YES	-40°C to 85°C	SOT-23	7-in. reel, 3000 pieces/reel
SS1344EUA	YES	-40°C to 85°C	TO-92	Bulk, 1000 pieces/bag
SS1344KSOT	YES	-40°C to 125°C	SOT-23	7-in. reel, 3000 pieces/reel
SS1344KUA	YES	-40°C to 125°C	TO-92	Bulk, 1000 pieces/bag
SS1344LSOT	YES	-40°C to 150°C	SOT-23	7-in. reel, 3000 pieces/reel
SS1344LUA	YES	-40°C to 150°C	TO-92	Bulk, 1000 pieces/bag